Attorney's Docket No. 42390P5769 # 19/E

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Gang Bai

Serial No. 09/109,261

Filed: June 30, 1998

For: A MULTI-LAYER GATE DIELECTRIC

Examiner: Warren, M.

Art Group: 2815

Jos Joseph 11/19/02 entered www.llaw 1/3/03

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TECHNOLOGY CENTER 2800

Box Non-Fee Amendment Assistant Commissioner for Patents Washington, D.C. 20231

AMENDMENT AND RESPONSE TO FINAL OFFICE ACTION

Dear Sir:

In response to the Final Office Action mailed September 10, 2002, in connection with the above referenced patent application, the Applicant respectfully requests entry of the following amendment and requests reconsideration in view of the following remarks. Entry is requested.

IN THE CLAIMS

Please cancel claims 11 and 1

Presented below are all the amended claims in clean unmarked form. The claims, in marked-up form, are presented as an attachment.

(Five Times Amended) A transistor device having a gate electrode overlying a gate dielectric formed directly on a semiconductor substrate, the gate dielectric comprising:

a first dielectric material having a first dielectric constant; and